NSN 5961-01-211-9233

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-211-9233 **Inclosure Material:** Plastic **Overall Length:** Between 1.060 inches and 1.187 inches **Overall Height:** Between 0.140 inches and 0.190 inches Overall Width: Between 0.380 inches and 0.420 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1.7 on-state voltage, peak **Current Rating Per Characteristic:** 16.00 amperes forward current, average of standard range **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius case **Test Data Document:** 13499-353-6612 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0